LOW VF SCHOTTKY DIODE MODULE TYPE

Features

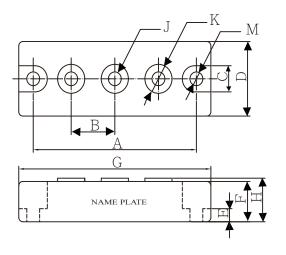
High Surge Capability Isolation Type Package Electrically Isolation base plate 400 Amp Rectifier 30 Volts

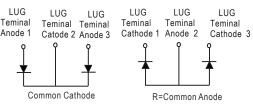
HEAVY THREE TOWER

Maximum Ratings

Operating Temperature: -40°C to +100°C Storage Temperature: -40 °C to +150 °C

Part Number	Maximum Recurrent Peak Reverse Voltage	Maximum RMS Voltage	Maximum DC Blocking Voltage
MBRTA40030(R)L	30V	21V	30V





Electrical Characteristics @ 25°C Unless Otherwise Specified

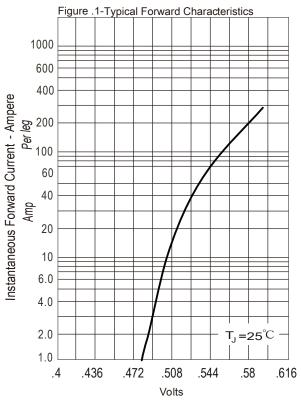
Average Forward Current (Per pkg)	I F(AV)	400A	TC=100°C
Peak Forward Surge Current (Per leg)	I _{FSM}	3000A	8.3ms, half sine
Maximum Instantaneous (Per leg) Forward Voltage	V_{F}	0.58V	^I FM=200 А; ТJ=25°С
Maximum Instantaneous Reverse Current At Rated DC Blocking Voltage (Per leg)	I _R	3mA 200mA	TJ= 25 °C TJ =100 °C
Maximum Thermal Resistance Junction To Case (Per leg)	Røjc	0.35 °C/W	

N	O	I	L	:

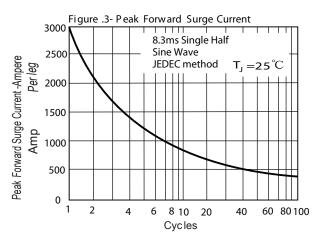
(1) Pulse Test: Pulse Width 300 μ sec. Duty Cycle < 2%

DIMENSIONS						
DIM	Inches		Millimeters			
	Min	Max	Min	Max		
A	3.150	NOM	80.01	NOM		
В	.872	.892	22.15	22.65		
С	.465	.479	11.82	12.18		
D	1.337	1.356	33.95	34.45		
Е	.230	.234	5.84	6.16		
F	.725	REF	18.42	REF		
G	3.668	3.768	93.17	95.71		
Н		.791		20.10		
J	1/4 -20 UNC FULL					
K	.509	.538	12.92	13.68		
М	.238	.258	6.05	6.55		

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Instantaneous Forward Voltage - Volts



Number Of Cycles At 60Hz - Cycles

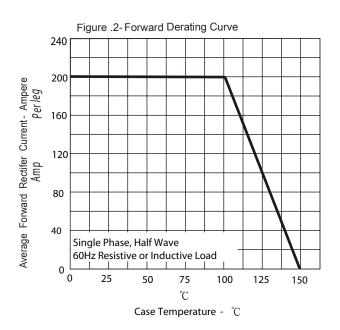
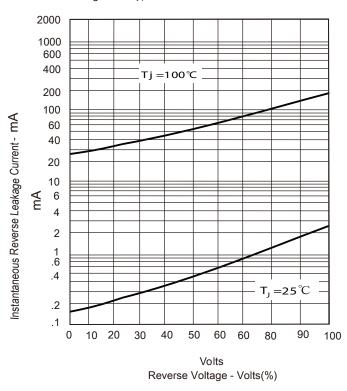


Figure .4-Typical Reverse Characteristics



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Nov. 2019

MBRTA40030(R)L

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